Dual 4-bit synchronous binary counter Rev. 5 — 14 February 2019

### 1. General description

The 74HC4520; 74HCT4520 are dual 4-bit internally synchronous binary counters with two clock inputs (nCP0 and nCP1). They have buffered outputs from all 4 bit positions (nQ0 to nQ3) and an asynchronous master reset input (nMR). The counter advances on the LOW-to-HIGH transition of nCP0 when nCP1 is HIGH. It also advances on the HIGH-to-LOW transition of nCP1 when nCP0 is LOW. Either nCP0 or nCP1 may be used as the clock input to the counter. The other clock input may be used as a clock enable input. A HIGH on nMR, resets the counter (nQ0 to nQ3 = LOW) independent of nCP0 and nCP1. Inputs include clamp diodes. It enables the use of current limiting resistors to interface inputs to voltages in excess of V<sub>CC</sub>.

## 2. Features and benefits

- Complies with JEDEC standard no. 7A
- Input levels:
  - For 74HC4520: CMOS level
  - For 74HCT4520: TTL level
- ESD protection:
  - HBM JESD22-A114F exceeds 2000 V
  - MM JESD22-A115-A exceeds 200 V
- Specified from -40 °C to +85 °C and -40 °C to +125 °C

### 3. Applications

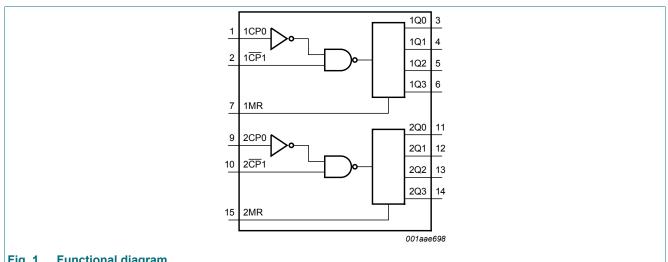
- Multistage synchronous counting
- Multistage asynchronous counting
- Frequency dividers

# 4. Ordering information

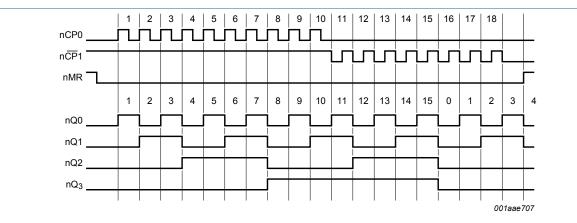
Table 1. Ordering in	Table 1. Ordering information						
Type number	Type number Package						
	Temperature range	Name	Description	Version			
74HC4520D	-40 °C to +125 °C	SO16	plastic small outline package; 16 leads;	SOT109-1			
74HCT4520D			body width 3.9 mm				
74HC4520PW	-40 °C to +125 °C	TSSOP16	plastic thin shrink small outline package; 16 leads; body width 4.4 mm	SOT403-1			

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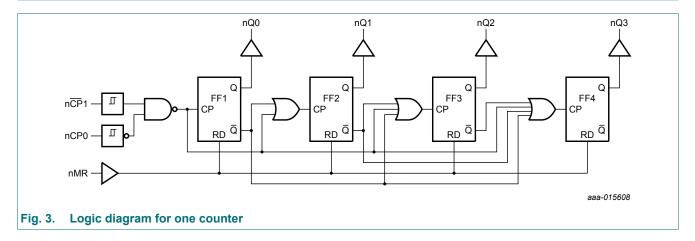
# 5. Functional diagram



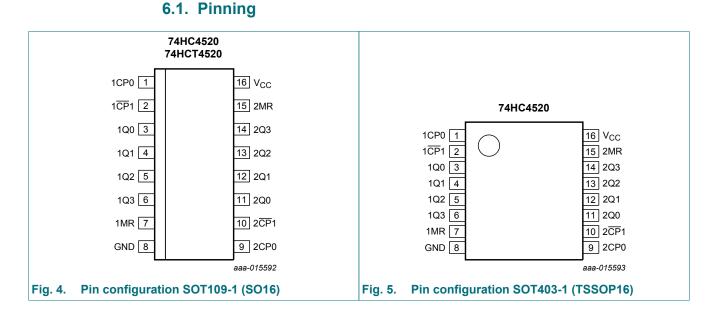
### Fig. 1. Functional diagram



#### Fig. 2. **Timing diagram**



# 6. Pinning information



### 6.2. Pin description

#### Table 2. Pin description

Symbol	Pin	Description
1CP0, 2CP0	1, 9	clock input (LOW-to-HIGH edge-triggered)
1 <u>CP</u> 1, 2 <u>CP</u> 1	2, 10	clock input (HIGH-to-LOW edge-triggered)
1Q0 to 1Q3	3, 4, 5, 6	output
1MR, 2MR	7, 15	asynchronous master reset input (active HIGH)
GND	8	ground (0 V)
2Q0 to 2Q3	11, 12, 13, 14	output
V <sub>CC</sub>	16	supply voltage

# 7. Functional description

### Table 3. Function table

H = HIGH voltage level; L = LOW voltage level; X = don't care;  $\uparrow = positive-going transition; \downarrow = negative-going transition.$ 

nCP0	nCP1	nMR	Mode
1	Н	L	counter advances
L	$\downarrow$	L	counter advances
$\downarrow$	Х	L	no change
Х	1	L	no change
1	L	L	no change
Н	Ļ	L	no change
Х	X	Н	nQ0 to nQ3 = LOW

74HC\_HCT4520

# 8. Limiting values

#### Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Мах	Unit
V <sub>CC</sub>	supply voltage		-0.5	+7.0	V
I <sub>IK</sub>	input clamping current	$V_{\rm I}$ < -0.5 V or $V_{\rm I}$ > $V_{\rm CC}$ + 0.5 V	-	±20	mA
I <sub>ок</sub>	output clamping current	$V_{\rm O}$ < -0.5 V or $V_{\rm O}$ > $V_{\rm CC}$ + 0.5 V	-	±20	mA
lo	output current	$V_{\rm O}$ = -0.5 V to $V_{\rm CC}$ + 0.5 V	-	±25	mA
I <sub>CC</sub>	supply current		-	50	mA
I <sub>GND</sub>	ground current		-50	-	mA
T <sub>stg</sub>	storage temperature		-65	+150	°C
P <sub>tot</sub>	total power dissipation	[1]	-	500	mW

[1] For SO16 package: above 70 °C the value of P<sub>tot</sub> derates linearly at 8 mW/K.

For TSSOP16 packages: above 60  $^\circ\text{C}$  the value of  $\mathsf{P}_{tot}$  derates linearly at 5.5 mW/K.

# 9. Recommended operating conditions

#### Table 5. Recommended operating conditions

Voltages are referenced to GND (ground = 0 V)

Symbol	Parameter Conditions		74HC4520			7	Unit		
			Min	Тур	Мах	Min	Тур	Max	
V <sub>CC</sub>	supply voltage		2.0	5.0	6.0	4.5	5.0	5.5	V
VI	input voltage		0	-	V <sub>CC</sub>	0	-	V <sub>CC</sub>	V
Vo	output voltage		0	-	V <sub>CC</sub>	0	-	V <sub>CC</sub>	V
T <sub>amb</sub>	ambient temperature		-40	+25	+125	-40	+25	+125	°C
Δt/ΔV	input transition rise and fall rate	V <sub>CC</sub> = 2.0 V	-	-	625	-	-	-	ns/V
		V <sub>CC</sub> = 4.5 V	-	1.67	139	-	1.67	139	ns/V
		V <sub>CC</sub> = 6.0 V	-	-	83	-	-	-	ns/V

# **10. Static characteristics**

#### **Table 6. Static characteristics**

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol Parameter		Conditions	25 °C			-40 °C to +85 °C		-40 °C to +125 °C		Unit
			Min	Тур	Max	Min	Max	Min	Max	
74HC45	20									
V <sub>IH</sub> HIGH-level	V <sub>CC</sub> = 2.0 V	1.5	1.2	-	1.5	-	1.5	-	V	
	input voltage	V <sub>CC</sub> = 4.5 V	3.15	2.4	-	3.15	-	3.15	-	V
		V <sub>CC</sub> = 6.0 V	4.2	3.2	-	4.2	-	4.2	-	V
V <sub>IL</sub>	LOW-level input voltage	V <sub>CC</sub> = 2.0 V	-	0.8	0.5	-	0.5	-	0.5	V
		V <sub>CC</sub> = 4.5 V	-	2.1	1.35	-	1.35	-	1.35	V
		V <sub>CC</sub> = 6.0 V	-	2.8	1.8	-	1.8	-	1.8	V

### Dual 4-bit synchronous binary counter

Symbol	Parameter	Conditions		25 °C			°C to 5 °C		°C to 5 °C	Unit
			Min	Тур	Max	Min	Max	Min	Max	
V <sub>OH</sub>	HIGH-level	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>								
	output voltage	I <sub>O</sub> = -20 μA; V <sub>CC</sub> = 2.0 V	1.9	2.0	-	1.9	-	1.9	-	V
		I <sub>O</sub> = -20 μA; V <sub>CC</sub> = 4.5 V	4.4	4.5	-	4.4	-	4.4	-	V
		I <sub>O</sub> = -20 μA; V <sub>CC</sub> = 6.0 V	5.9	6.0	-	5.9	-	5.9	-	V
		I <sub>O</sub> = -4.0; V <sub>CC</sub> = 4.5 V	3.98	4.32	-	3.84	-	3.7	-	V
		I <sub>O</sub> = -5.2; V <sub>CC</sub> = 6.0 V	5.48	5.81	-	5.34	-	5.2	-	V
V <sub>OL</sub>	LOW-level	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>								
	output voltage	I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 2.0 V	-	0	0.1	-	0.1	-	0.1	V
		I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 4.5 V	-	0	0.1	-	0.1	-	0.1	V
		I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 6.0 V	-	0	0.1	-	0.1	-	0.1	V
		I <sub>O</sub> = 4.0 mA; V <sub>CC</sub> = 4.5 V	-	0.15	0.26	-	0.33	-	0.4	V
		I <sub>O</sub> = 5.2 mA; V <sub>CC</sub> = 6.0 V	-	0.16	0.26	-	0.33	-	0.4	V
I <sub>I</sub>	input leakage current	$V_1 = V_{CC}$ or GND; $V_{CC} = 6.0$ V	-	-	±0.1	-	±1.0	-	±1.0	μA
I <sub>CC</sub>	supply current	$V_1 = V_{CC}$ or GND; $I_0 = 0$ A; $V_{CC} = 6.0$ V	-	-	8.0	-	80.0	-	160.0	μA
CI	input capacitance		-	3.5	-	-	-	-	-	pF
74HCT4	520		1							
V <sub>IH</sub>	HIGH-level input voltage	V <sub>CC</sub> = 4.5 V to 5.5 V	2.0	1.6	-	2.0	-	2.0	-	V
V <sub>IL</sub>	LOW-level input voltage	$V_{CC}$ = 4.5 V to 5.5 V	-	1.2	0.8	-	0.8	-	0.8	V
V <sub>OH</sub>	HIGH-level	$V_{I} = V_{IH} \text{ or } V_{IL}; V_{CC} = 4.5 \text{ V}$								
	output voltage	I <sub>O</sub> = -20 μA	4.4	4.5	-	4.4	-	4.4	-	V
		I <sub>O</sub> = -4.0 mA	3.98	4.32	-	3.84	-	3.7	-	V
V <sub>OL</sub>	LOW-level	$V_{I}$ = $V_{IH}$ or $V_{IL}$ ; $V_{CC}$ = 4.5 V								
	output voltage	I <sub>O</sub> = 20 μA	-	0	0.1	-	0.1	-	0.1	V
		I <sub>O</sub> = 4.0 mA	-	0.15	0.26	-	0.33	-	0.4	V
lı	input leakage current	$V_1 = V_{CC}$ or GND; $V_{CC} = 5.5 V$	-	-	±0.1	-	±1.0	-	±1.0	μA
I <sub>CC</sub>	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 5.5$ V	-	-	8.0	-	80.0	-	160.0	μA
ΔI <sub>CC</sub>	additional supply current	per input pin; $V_I = V_{CC} - 2.1 V$ ; other inputs at $V_{CC}$ or GND; $V_{CC} = 4.5 V$ to 5.5 V; $I_0 = 0 A$								
		pin nCP0, nCP1	-	80	288	-	360	-	392	μA
		pin nMR	-	150	540	-	675	-	735	μA
CI	input capacitance		-	3.5	-	-	-	-	-	pF

# **11. Dynamic characteristics**

### Table 7. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V);  $C_L$  = 50 pF unless otherwise specified; for test circuit, see Fig. 8.

Symbol	Parameter	Conditions		25 °C			°C to 5 °C	-40 °C to +125 °C		Unit
			Min	Тур	Max	Min	Max	Min	Max	-
74HC45	20									
t <sub>pd</sub>	propagation	nCP0 to nQn; see <u>Fig. 6</u>	[1]							
	delay	V <sub>CC</sub> = 2.0 V	-	77	240	-	300	-	360	ns
		V <sub>CC</sub> = 4.5 V	-	28	48	-	60	-	72	ns
		V <sub>CC</sub> = 5.0 V; C <sub>L</sub> = 15 pF	-	24	-	-	-	-	-	ns
		V <sub>CC</sub> = 6.0 V	-	22	41	-	51	-	61	ns
		nCP1 to nQn; see Fig. 6	[1]							
		V <sub>CC</sub> = 2.0 V	-	77	240	-	300	-	360	ns
		V <sub>CC</sub> = 4.5 V	-	28	48	-	60	-	72	ns
		V <sub>CC</sub> = 5.0 V; C <sub>L</sub> = 15 pF	-	24	-	-	-	-	-	ns
		V <sub>CC</sub> = 6.0 V	-	22	41	-	51	-	61	ns
		nMR to nQn; see <u>Fig. 6</u>								
	propagation delay	V <sub>CC</sub> = 2.0 V	-	44	150	-	190	-	225	ns
	uciay	V <sub>CC</sub> = 4.5 V	-	16	30	-	38	-	45	ns
	V <sub>CC</sub> = 5.0 V; C <sub>L</sub> = 15 pF	-	13	-	-	-	-	-	ns	
		V <sub>CC</sub> = 6.0 V	-	13	26	-	33	-	38	ns
t <sub>t</sub> transit time	transition	nQn; see <u>Fig. 6</u>	[2]							
	time	V <sub>CC</sub> = 2.0 V	-	19	75	-	95	-	110	ns
		V <sub>CC</sub> = 4.5 V	-	7	15	-	19	-	22	ns
		V <sub>CC</sub> = 6.0 V	-	6	13	-	16	-	19	ns
t <sub>W</sub>	pulse width	nCP0, n <del>CP</del> 1 HIGH or LOW; see <u>Fig. 7</u>								
		V <sub>CC</sub> = 2.0 V	80	22	-	100	-	120	-	ns
		V <sub>CC</sub> = 4.5 V	16	8	-	20	-	24	-	ns
		V <sub>CC</sub> = 6.0 V	14	6	-	17	-	20	-	ns
		nMR HIGH; see Fig. 7								
		V <sub>CC</sub> = 2.0 V	120	39	-	150	-	180	-	ns
		V <sub>CC</sub> = 4.5 V	24	14	-	30	-	36	-	ns
		V <sub>CC</sub> = 6.0 V	20	11	-	26	-	31	-	ns
t <sub>rec</sub>	recovery time	nMR to nCP0, nCP1; see Fig. 7								
		V <sub>CC</sub> = 2.0 V	0	-28	-	0	-	0	-	ns
		V <sub>CC</sub> = 4.5 V	0	-10	-	0	-	0	-	ns
		V <sub>CC</sub> = 6.0 V	0	-8	-	0	-	0	-	ns
t <sub>su</sub>	set-up time	nCP0 to nCP1; nCP1 to nCP0; see <u>Fig. 6</u>								
		V <sub>CC</sub> = 2.0 V	80	14	-	100	-	120	-	ns
		V <sub>CC</sub> = 4.5 V	16	5	-	20	-	24	-	ns
		V <sub>CC</sub> = 6.0 V	14	4	-	17	-	20	-	ns

### Dual 4-bit synchronous binary counter

Symbol	Parameter	Conditions		25 °C			°C to 5 °C		°C to 5 °C	Unit
			Min	Тур	Max	Min	Max	Min	Max	1
f <sub>max</sub>	maximum	nCP0, n <u>CP</u> 1; see <u>Fig. 7</u>								
	frequency	V <sub>CC</sub> = 2.0 V	6	19	-	4.8	-	4	-	MHz
		V <sub>CC</sub> = 4.5 V	30	58	-	24	-	20	-	MHz
		V <sub>CC</sub> = 5.0 V; C <sub>L</sub> = 15 pF	-	68	-	-	-	-	-	MHz
		V <sub>CC</sub> = 6.0 V	35	69	-	28	-	24	-	MHz
C <sub>PD</sub>	power dissipation capacitance	$V_{I} = GND$ to $V_{CC}$ ; $V_{CC} = 5 V$ ; [3] $f_{i} = 1 MHz$	-	29	-	-	-	-	-	pF
74HCT4	520						1		1	
t <sub>pd</sub>	propagation	nCP0 to nQn; see Fig. 6 [1]								
	delay	V <sub>CC</sub> = 4.5 V	-	28	53	-	66	-	80	ns
		V <sub>CC</sub> = 5.0 V; C <sub>L</sub> = 15 pF	-	24	-	-	-	-	-	ns
		nCP1 to nQn; see Fig. 6 [1]								
		V <sub>CC</sub> = 4.5 V	-	25	53	-	66	-	80	ns
		V <sub>CC</sub> = 5.0 V; C <sub>L</sub> = 15 pF	-	24	-	-	-	-	-	ns
t <sub>PHL</sub>	HIGH to LOW	nMR to nQn; see <u>Fig. 6</u>								
	propagation	V <sub>CC</sub> = 4.5 V	-	16	35	-	44	-	53	ns
	delay	V <sub>CC</sub> = 5.0 V; C <sub>L</sub> = 15 pF	-	13	-	-	-	-	-	ns
t <sub>t</sub>	transition	nQn; see <u>Fig. 6</u> [2]								
	time	V <sub>CC</sub> = 4.5 V	-	7	15	-	19	-	22	ns
t <sub>W</sub>	pulse width	nCP0, nCP1 HIGH or LOW; see <u>Fig. 7</u>								
		V <sub>CC</sub> = 4.5 V	20	10	-	25	-	30	-	ns
		nMR HIGH; see <u>Fig. 7</u>								
		V <sub>CC</sub> = 4.5 V	20	12	-	25	-	30	-	ns
t <sub>rec</sub>	recovery time	nMR to nCP0, nCP1; see Fig. 7								
		V <sub>CC</sub> = 4.5 V	0	-8	-	0	-	0	-	ns
t <sub>su</sub>	set-up time	nCP0 to nCP1; nCP1 to nCP0; see <u>Fig. 6</u>								
		V <sub>CC</sub> = 4.5 V	16	6	-	20	-	24	-	ns
f <sub>max</sub>	maximum	nCP0, n <del>CP</del> 1; see <u>Fig. 7</u>								
	frequency	V <sub>CC</sub> = 4.5 V	30	58	-	24	-	20	-	MHz
		V <sub>CC</sub> = 5.0 V; C <sub>L</sub> = 15 pF	-	64	-	-	-	-	-	MHz
C <sub>PD</sub>	power dissipation capacitance	$V_{l} = GND \text{ to } V_{CC} - 1.5 \text{ V}; V_{CC} = 5 \text{ V}; $ [3] $f_{i} = 1 \text{ MHz}$		24	-	-	-	-	-	pF

[1]  $t_{pd}$  is the same as  $t_{PHL}$  and  $t_{PLH}$ . [2]  $t_t$  is the same as  $t_{THL}$  and  $t_{TLH}$ . [3]  $C_{PD}$  is used to determine the dynamic power dissipation (P<sub>D</sub> in µW):  $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma(C_L \times V_{CC}^2 \times f_o)$  where:

 $f_i$  = input frequency in MHz;

 $f_o$  = output frequency in MHz;

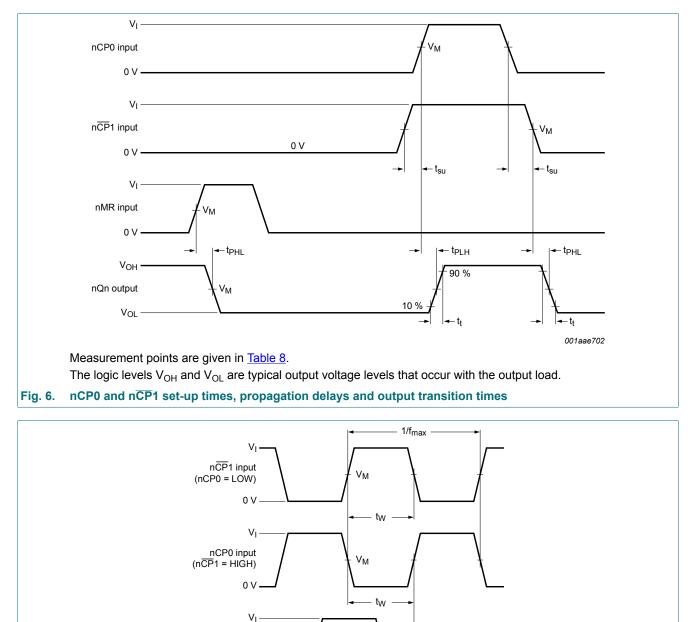
 $C_L$  = output load capacitance in pF;

V<sub>CC</sub> = supply voltage in V;

N = number of inputs switching;

 $\Sigma(C_L \times V_{CC}^2 \times f_o)$  = sum of outputs.

### Dual 4-bit synchronous binary counter



### 11.1. Waveforms and test circuit

Measurement points are given in <u>Table 8</u>.

nMR input

0 V

The logic levels  $V_{\text{OH}}$  and  $V_{\text{OL}}$  are typical output voltage levels that occur with the output load.

 $V_{\mathsf{M}}$ 

tw

t<sub>rec</sub>

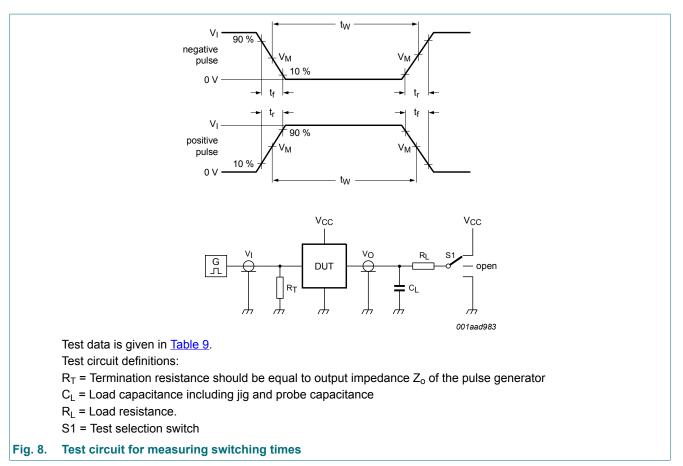
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#### Fig. 7. nMR recovery time, minimum nCP0, nCP1, nMR pulse widths and maximum frequency

### Table 8. Measurement points

Туре	Input	Output	
	V <sub>M</sub>	V <sub>I</sub>	V <sub>M</sub>
74HC4520	0.5 × V <sub>CC</sub>	GND to V <sub>CC</sub>	$0.5 \times V_{CC}$
74HCT4520	1.3 V	GND to 3 V	1.3 V

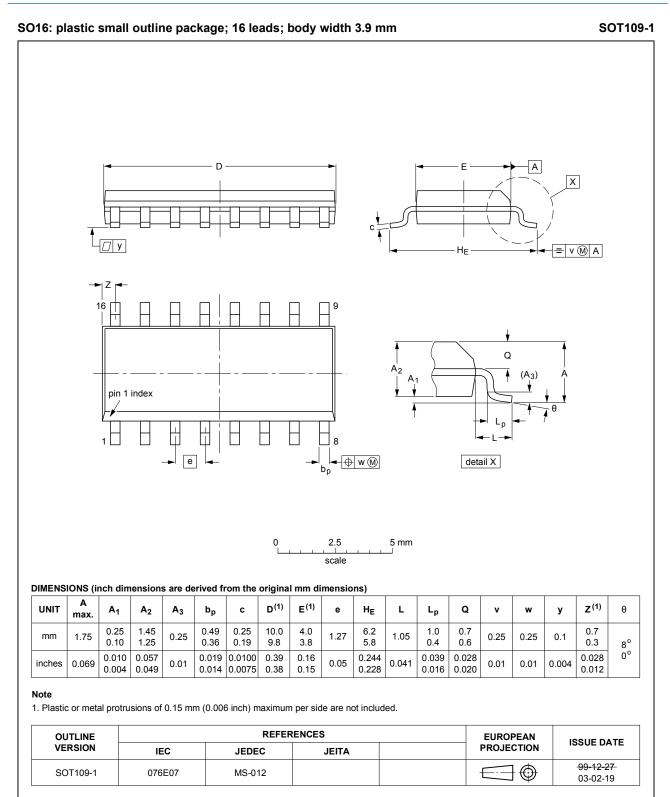
### Dual 4-bit synchronous binary counter



#### Table 9. Test data

Туре	Input L		Load	Load			
	VI	t <sub>r</sub> , t <sub>f</sub>	CL	RL	t <sub>PHL</sub> , t <sub>PLH</sub>		
74HC4520	GND to V <sub>CC</sub>	6 ns	15 pF, 50 pF	1 kΩ	open		
74HCT4520	GND to 3 V	6 ns	15 pF, 50 pF	1 kΩ	open		

# 12. Package outline



### Fig. 9. Package outline SOT109-1 (SO16)

74HC\_HCT4520

### Dual 4-bit synchronous binary counter

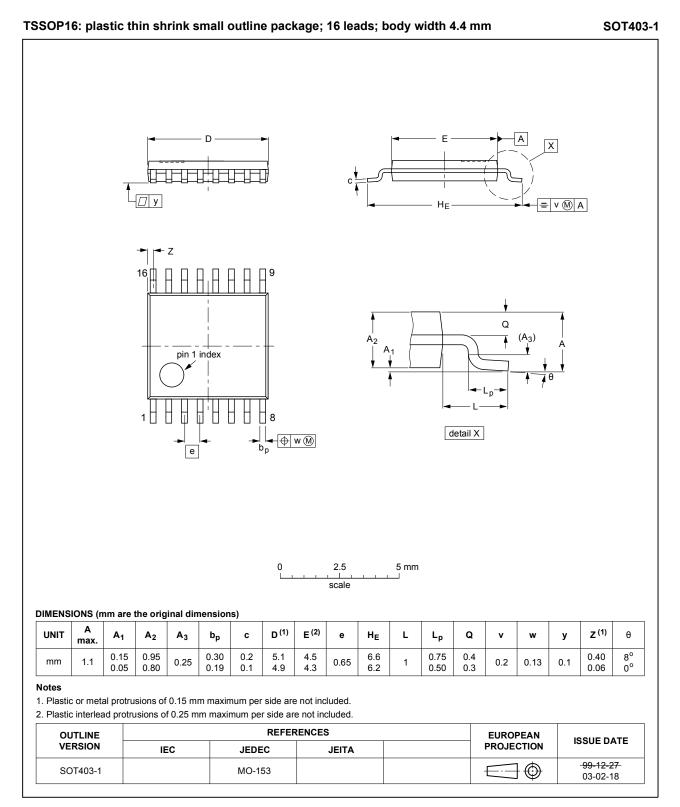


Fig. 10. Package outline SOT403-1 (TSSOP16)

<sup>74</sup>HC\_HCT4520

# 13. Abbreviations

Table 10. Abbreviations					
Acronym	Description				
CMOS	Complementary Metal-Oxide Semiconductor				
DUT	Device Under Test				
ESD	ElectroStatic Discharge				
НВМ	Human Body Model				
MM	Machine Model				
TTL	Transistor-Transistor Logic				

# 14. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes	
74HC_HCT4520 v.5	20190214	Product data sheet	-	74HC_HCT4520 v.4	
Modifications:	<ul> <li>The format of this data sheet has been redesigned to comply with the identity guidelines of Nexperia.</li> <li>Legal texts have been adapted to the new company name where appropriate.</li> <li>Type numbers 74HC4520DB and 74HCT4520DB (SOT338-1) removed.</li> </ul>				
74HC_HCT4520 v.4	20160510	Product data sheet	-	74HC_HCT4520 v.3	
Modifications:	• Type numbers 74HC4520N and 74HCT4520N (SOT38-4) removed.				
74HC_HCT4520 v.3	20141204	Product data sheet	-	74HC_HCT4520_CNV v.2	
Modifications:	<ul> <li>The format of this data sheet has been redesigned to comply with the new identity guidelines of NXP Semiconductors.</li> <li>Legal texts have been adapted to the new company name where appropriate.</li> </ul>				
74HC_HCT4520_CNV v.2	19930927	Product specification	-	-	

# 15. Legal information

#### Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

 Please consult the most recently issued document before initiating or completing a design.

- [2] The term 'short data sheet' is explained in section "Definitions".
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the internet at <u>https://www.nexperia.com</u>.

#### **Definitions**

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